



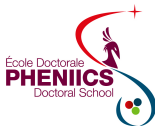
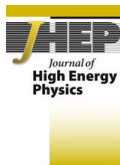
Feasibility of measuring the magnetic dipole moments of the charm baryons at the LHC using bent crystals

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1 Magnetic dipole moment of charm baryons

- Introduction
- Principals of measurement

2 Deflection by a bent crystal

- Planar channeling
- Computational model
- Phenomenological formula

3 Sensitivity study

- Error of measured g -factor
- Crystal parameters optimization
- Data taking time

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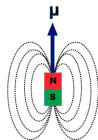
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Λ_c^+ magnetic dipole moment measurement

$$\vec{\mu} = \frac{g}{2} \frac{e}{m} \vec{S}, \quad \vec{S} = \frac{\hbar}{2} \vec{\sigma}$$



Particle	g -factor
electron	-2.002 319 304 361 82(52)
muon	-2.002 331 84 18(13)
neutron	-3.826 085 45(90)
proton	+5.585 694 702(17)
Σ^+	+2.458(10)

not measured for charmed, beauty baryons

- $|g| \approx 2 \rightarrow$ a point-like (Dirac particle)
- $|g| \not\approx 2 \rightarrow$ a composite structure
- $g(\Lambda_c^+(u, d, c)) \approx g_c$
- $g_c = 2 \rightarrow g(\Lambda_c^+) = 1.80-2.05$

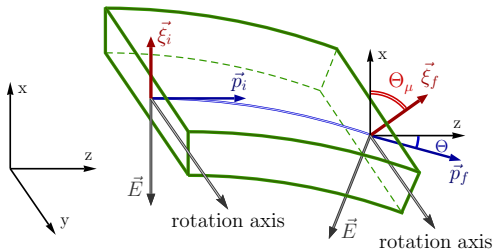
How? Induce the precession of the polarization vector by the strong magnetic field

Problem: $c\tau(\Lambda_c^+) \sim 60 \mu\text{m}$ — far too short for measuring

Solution: conventional \vec{B} replaced by bent crystal

V.G. Baryshevsky, Pis'ma Zh. Tekh. Fiz., 5 (1979)

Precession of magnetic dipole moment: principals of measurement



$$\Theta_\mu \approx \gamma \left(\frac{g}{2} - 1 \right) \Theta$$

$$\Theta = \frac{L_{\text{crys}}}{R}$$

$$\vec{\xi}_i = \xi (1, 0, 0)$$

$$\vec{\xi}_f = \xi (\cos \Theta_\mu, 0, \sin \Theta_\mu)$$

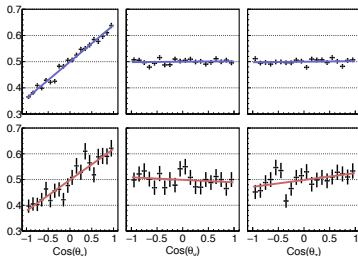
Angular distribution of decay products:

$$\frac{1}{N} \frac{dN}{d \cos \vartheta_k} = \frac{1}{2} (1 + \alpha \xi_k \cos \vartheta_k) \Big|_{k=x,y,z}$$

Need:

$\xi \neq 0$ — Λ_c^+ polarized at the production

$\alpha \neq 0$ — keep polarization at the decay



Precession of magnetic dipole moment: angular analysis

$$\Delta g = \frac{1}{\alpha_j |\xi| \Theta} \sqrt{\frac{12}{\Phi t \frac{\Gamma_j}{\Gamma} \eta_{\text{det}}^{(j)} \int \frac{\partial N_{\text{tar+crys}}}{\partial \varepsilon} \gamma^2 d\varepsilon}}$$

$|\xi|$ – polarization

Φ – proton flux

t – data taking time

- Decay channel dependent

α_j – weak-decay parameter

Γ_j/Γ – branching fraction

$\eta_{\text{det}}^{(j)}$ – detection efficiency

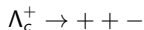
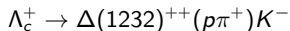
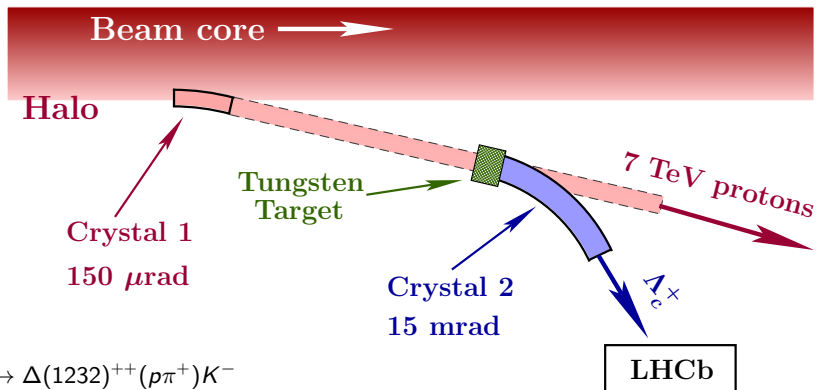
- Crystal dependent

Θ – deflection angle

$\frac{\partial N_{\text{tar+crys}}}{\partial \varepsilon}$ – normalized spectra
of deflected particles
(per incident proton)

Λ_c^+ magnetic dipole moment measurement: Exp. setup

This double crystal scheme is now under study with a 2 years program by UA9 at SPS.



EOI (CERN 2016): L. Burmistrov *et al.*, Tech. Rep. CERN-SPSC-2016-030. SPSC-EOI-012;
Physics Beyond Colliders Kickoff Workshop (CERN 2016): A. Stocchi *et al.*; W. Scandale *et al.*

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- Principals of measurement

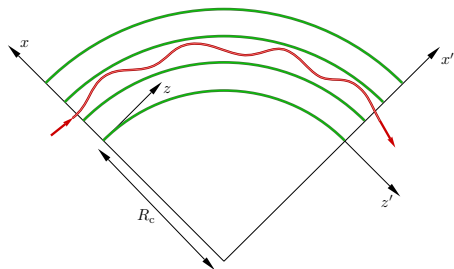
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Channeling in a bent crystal

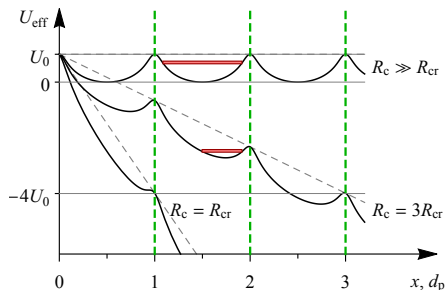


Effective potential

$$U_{\text{eff}}(x) = U^{\pm}(x) - x \frac{\varepsilon}{R_c}$$

Critical radius

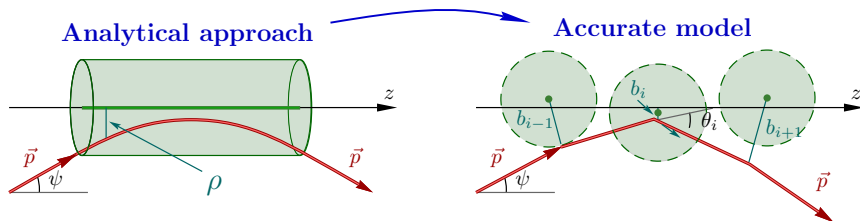
$$R_{\text{cr}} = \frac{\varepsilon}{U'_x} \approx d_p \frac{\varepsilon}{4 U_0}$$



Acceptance angle

$$\theta_{\text{acc}} = \sqrt{\frac{2 U_{\text{eff}}}{\varepsilon}} \left(1 - \frac{\varepsilon}{R U'_x} \right)$$

Computational model



Binary collision model (scattering on atoms)

- Most natural way of taking into account the thermal vibration of atoms
- Deflection angle of particle is calculated on each consequent atom
- Displacement of nearest atom due to the thermal vibration is drawn by normal distribution

Aggregate collisions model (scattering on electrons)

- Multiple scattering with modified radiation length

Binary collision model

Deflection angle of particle on each consequent atom:

$$\Delta\vec{\vartheta}_a(\vec{r}) = \frac{Z e^2 \vec{r}}{\varepsilon r^2} \sum_{i=1}^3 \alpha_i \beta_i^2 K_0(\beta_i r), \quad \Delta\vec{\vartheta}_n = \sum_{k=1}^N \Delta\vec{\vartheta}_a(\vec{r}_k).$$

Displacement of nearest atom due to the thermal vibration:

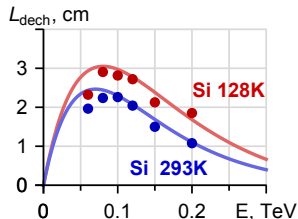
$$P(u_x) du_x = \frac{1}{\sqrt{2\pi u_x^2}} \exp\left(-\frac{u_x^2}{2u_x^2}\right) du_x$$

Aggregate collisions model

Multiple scattering on the electron subsystem

$$\sqrt{\vartheta_x^2} = \frac{13.6 \text{ MeV}}{\varepsilon} \sqrt{\frac{\Delta l}{X_0}} \left[1 + 0.038 \ln\left(\frac{\Delta l}{X_0}\right) \right],$$

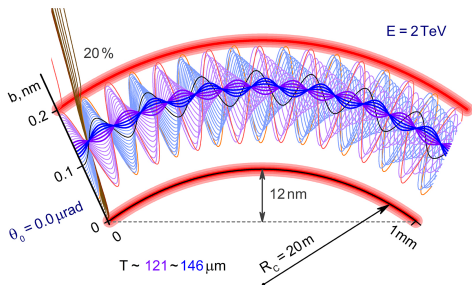
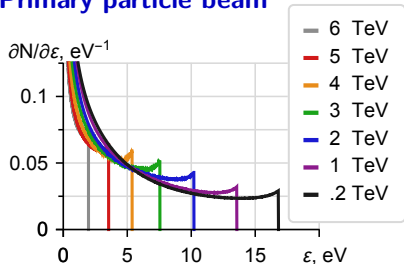
$$\frac{\Delta l}{X_0} = \frac{4 e^6}{m^2} \ln(m d_p) \int_0^{\Delta l} \bar{n}_e(l) dl.$$



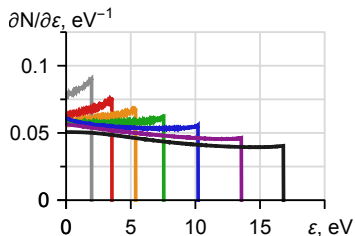
Forster J S et al.
Nucl. Phys. B 318 301 (1989)

Channeling in a bent crystal: primary vs secondary beams

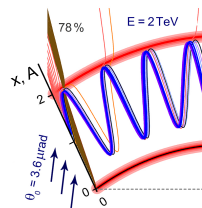
Primary particle beam



Secondary particle beam



- Primary particle beam
 - Parallel beam
 - Monochromatic
- Secondary particle beam
 - Uniform angular distribution
 - Wide energy distribution
 - Populated high energy states



Deflection efficiency: phenomenological formula

$$\eta_{\text{def}}(\varepsilon, R, L) = \eta_{\text{ang}} \eta_{\text{ch}} (1 - \eta_{\text{dech}})$$

– deflected fraction
of secondary beam

Angular acceptance

$$\eta_{\text{ang}} = \text{erf}(\sqrt{2} \theta_{\text{acc}} \gamma)$$

$$\theta_{\text{acc}} = \sqrt{\frac{2 U_{\text{eff}}}{\varepsilon}} \left(1 - \frac{\varepsilon}{R} \frac{1}{U'_x}\right)$$

Channeling acceptance

$$\eta_{\text{ch}}(\varepsilon, R) = \frac{\eta_{\text{str}}}{1 + \left(\frac{\varepsilon}{R} \frac{1}{U'_x k_{\theta}}\right)^2}$$

Dechanneling probability

$$\eta_{\text{dech}}(\varepsilon, R, L) = 1 - e^{-\sqrt{\frac{L}{L_{\text{dech}}(\varepsilon, R)}}}$$

Dechanneling length

$$L_{\text{dech}}(\varepsilon, R) = L_{\text{max}} \frac{\varepsilon}{\varepsilon_{\text{max}}} e^{1 - \frac{\varepsilon}{\varepsilon_{\text{max}}}}$$

$$L_{\text{max}} = k_{\text{dech}} R \left(\frac{R_0}{R}\right)^{b_{\text{dech}}}$$

$$\varepsilon_{\text{max}} = R F_{\text{dech}}$$

$U_{\text{eff}}, U'_x, \eta_{\text{str}}, k_{\theta}, k_{\text{dech}}, R_0, b_{\text{dech}}, F_{\text{dech}}$ were found for Si, Ge and Ge* crystals

Spectra of deflected Λ_c^+ produced by 7 TeV protons

Initial spectra (Pythia v8.1)

- credit to Leonid Burmistrov
- p - N collision in a fixed target
- normalized to one produced Λ_c^+

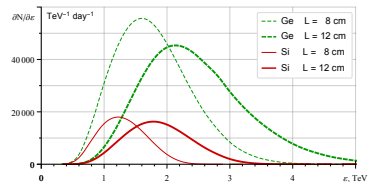
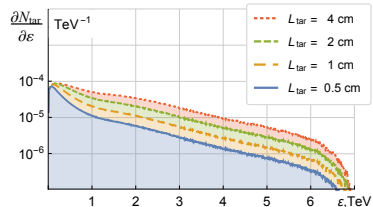
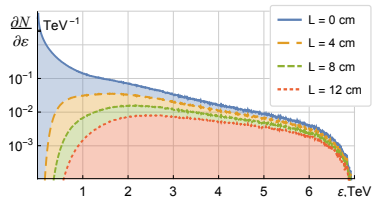
Spectra after the target

$$\frac{\partial N_{\text{tar}}}{\partial \varepsilon} = \frac{\rho N_A A_{\text{tar}}}{M_{\text{tar}}} \sigma_{\Lambda_c} \frac{\partial N}{\partial \varepsilon} \int_0^{L_{\text{tar}}} e^{-\frac{L}{c\tau\gamma}} dL$$

- normalized to one initial proton

Spectra of deflected Λ_c^+

$$\frac{\partial N_{\text{tar+crys}}}{\partial \varepsilon} = \frac{\partial N_{\text{tar}}}{\partial \varepsilon} \eta_{\text{def}} e^{-\frac{L_{\text{crys}}}{c\tau\gamma}}$$



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Sensitivity study: error of measured g -factor. List of parameters.

$$\Delta g = \frac{1}{\alpha_j |\xi| \Theta} \sqrt{\frac{12}{\Phi t \frac{\Gamma_j}{\Gamma} \eta_{\text{det}}^{(j)} \int \frac{\partial N_{\text{tar+crys}}}{\partial \varepsilon} \gamma^2 d\varepsilon}}$$

$|\xi|$ – polarization

Φ – proton flux

t – data taking time

- Decay channel dependent

α_j – weak-decay parameter

Γ_j/Γ – branching fraction

$\eta_{\text{det}}^{(j)}$ – detection efficiency

- Crystal dependent

Θ – deflection angle

$\frac{\partial N_{\text{tar+crys}}}{\partial \varepsilon}$ – normalized spectra
of deflected particles
(per incident proton)

Optimization of the crystal parameters

Sensitivity study: Crystal parameters optimization

$$\Delta g = \frac{1}{\alpha_j |\xi| \Theta} \sqrt{\frac{12}{\Phi t \frac{\Gamma_j}{\Gamma} \eta_{\text{det}}^{(j)} \int \frac{\partial N_{\text{tar+crys}}}{\partial \varepsilon} \gamma^2 d\varepsilon}}$$

Relative crystal efficiency:

$$\eta_{\text{rel}} = \frac{t_0}{t} = \frac{\Theta^2 \int \frac{\partial N_{\text{tar+crys}}}{\partial \varepsilon} \gamma^2 d\varepsilon}{\Theta_0^2 \int \frac{\partial N_{\text{tar+crys},0}}{\partial \varepsilon} \gamma^2 d\varepsilon}$$

t – data taking time ('0' indicates the reference crystal)

Θ – deflection angle

$\frac{\partial N_{\text{tar+crys}}}{\partial \varepsilon}$ – normalized spectra of deflected particles (per incident proton)

Optimal crystal for measuring the MDM of Λ_c^+

Relative crystal efficiency

$$\eta_{\text{rel}} = \frac{t_0}{t} = \frac{\Theta^2 \int \frac{\partial N_{\text{tar+crys}}}{\partial \varepsilon} \gamma^2 d\varepsilon}{\Theta_0^2 \int \frac{\partial N_{\text{tar+crys},0}}{\partial \varepsilon} \gamma^2 d\varepsilon}$$

Optimal Length: $L_{\text{crys}} = 8\text{--}11\text{ cm}$

Optimal Curvature:

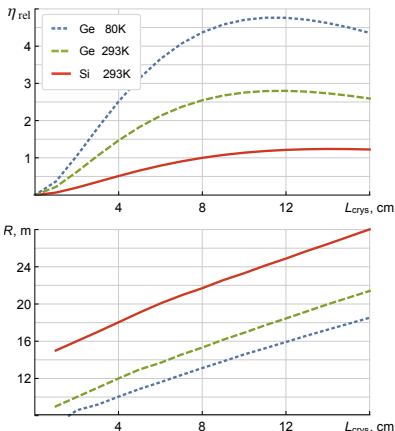
Si 293K $R = 22\text{ m}$ $\Theta_0 \approx 3.6\text{ mrad}$

Ge 293K $R = 15\text{ m}$ $\Theta \approx 5.3\text{ mrad}$

Ge 80K $R = 13\text{ m}$ $\Theta \approx 6.2\text{ mrad}$

Optimal Crystal:

$$\frac{\eta_{\text{rel}}(\text{Ge})}{\eta_{\text{rel}}(\text{Si})} \approx 2.5 \quad \eta_{\text{rel}}(\text{Ge}) \approx 4.5$$



Optimal crystal for measuring the MDM of Λ_c^+ at LHCb

Relative crystal efficiency

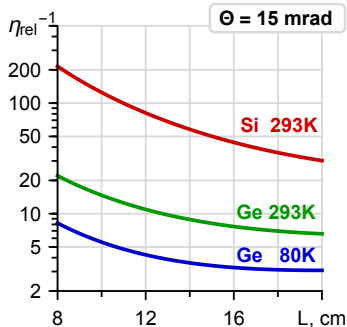
$$\eta_{\text{rel}} = \frac{t_0}{t} = \frac{\Theta^2 \int \frac{\partial N_{\text{tar+crys}}}{\partial \epsilon} \gamma^2 d\epsilon}{\Theta_0^2 \int \frac{\partial N_{\text{tar+crys},0}}{\partial \epsilon} \gamma^2 d\epsilon}$$

relative to the reference Si configuration:

– Si 293K $L = 8 \text{ cm}$ $\Theta_0 \approx 3.6 \text{ mrad}$

But:

- silicon is more mature technology
- 8 cm is possible (difficulties with longer crystals)
- Acceptance of “LHCb” $\sim 15 \text{ mrad}$



work is ongoing

η_{rel}^{-1} (Si) $\approx 50\text{--}200$

η_{rel}^{-1} (Ge) $\approx 8\text{--}22$

η_{rel}^{-1} (Ge) $\approx 3\text{--}8$

Absolute statistical error of measured g -factor.

Decay channel parameters

$$\Delta g = \frac{1}{\alpha_j |\xi| \Theta} \sqrt{\frac{12}{\Phi t \frac{\Gamma_j}{\Gamma} \eta_{\text{det}}^{(j)} \int \frac{\partial N_{\text{tar+crys}}}{\partial \varepsilon} \gamma^2 d\varepsilon}}$$

$$c\tau(\Lambda) \approx 8 \text{ cm}$$

Decay channel	Weak-decay parameter α_j	Branching fraction $\Gamma_j/\Gamma, \%$	Detection efficiency $\eta_{\text{det}}^{(j)}, \%$
$\Lambda_c^+ \rightarrow \Lambda(p \pi^-) \pi^+$	-0.91(15)	0.7(2)	0.2
$\Lambda_c^+ \rightarrow \Lambda(p \pi^-) e^+(\mu^+) \nu_{e(\mu)}$	-0.86(04)	1.3(4)	0.2
$\Lambda_c^+ \rightarrow \Delta(1232)^{++}(p \pi^+) K^-$	-0.67(30)	0.9(3)	3
$\Lambda_c^+ \rightarrow \bar{K}^*(892)^0(K^- \pi^+) p$	-0.55(35)	1.6(5)	3
$\Lambda_c^+ \rightarrow \Lambda(1520)(p K^-) \pi^+$	-0.11(60)	0.8(3)	3

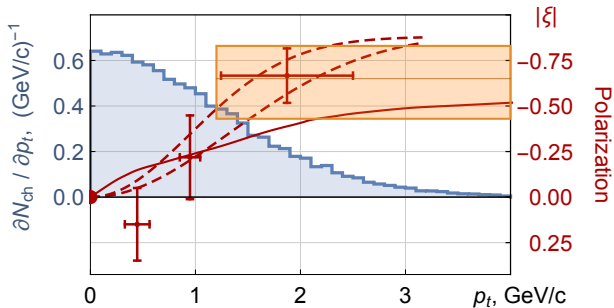
Absolute statistical error of measured g -factor.

Polarization as a function of transverse momentum.

$$\Delta g = \frac{1}{\alpha_j |\xi| \Theta} \sqrt{\frac{12}{\Phi t \frac{\Gamma_j}{\Gamma} \eta_{\text{det}}^{(j)} \int \frac{\partial N_{\text{tar+crys}}}{\partial \epsilon} \gamma^2 d\epsilon}}$$

$$\sqrt{|\xi|_{\text{th}}^2} = -0.37$$

$$\sqrt{|\xi|_{\text{ex}}^2} = -0.40(5)$$



- J. G. Korner, et al.
Z. Phys., C2:117, 1979
- + E. M. Aitala et al.
Phys. Lett., B471:449
2000
- Fitted exp. data
- Gary R. Goldstein.
FNAL, Batavia, Illinois
p.132–136, 1999.

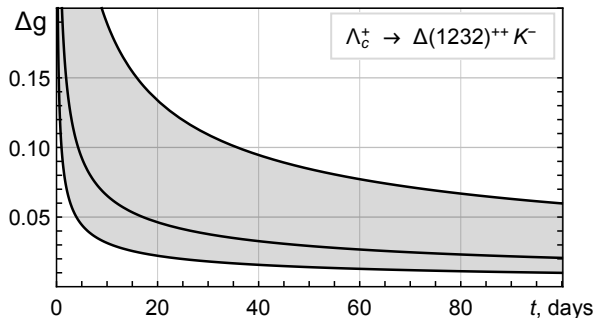
Absolute statistical error of measured g -factor

as a function of data taking time

$$\Delta g = \frac{1}{\alpha_j |\xi| \Theta} \sqrt{\frac{12}{\Phi t \frac{\Gamma_j}{\Gamma} \eta_{\text{det}}^{(j)} \int \frac{\partial N_{\text{tar+crys}}}{\partial \varepsilon} \gamma^2 d\varepsilon}}$$

Reference crystal:

Si $L = 8$ cm
 $R = 22$ m



$\Delta g = 0.1$

$t \sim 1 - 30$ days

$\bar{t} \sim 5$ days

This proposal is now considered in LHCb and so we use the required parameters

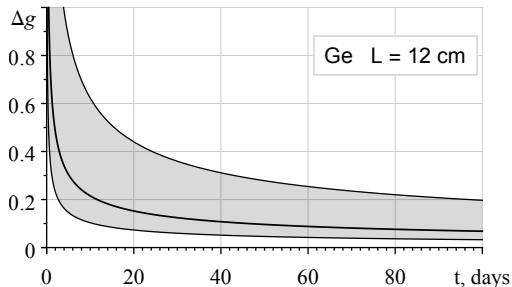
Absolute statistical error of measured g -factor

as a function of data taking time

$$\Delta g = \frac{1}{\alpha_j |\xi| \Theta} \sqrt{\frac{12}{\Phi t \frac{\Gamma_j}{\Gamma} \eta_{\text{det}}^{(j)} \int \frac{\partial N_{\text{tar+crys}}}{\partial \varepsilon} \gamma^2 d\varepsilon}}$$

Ge $L = 12$ cm

$R = 8$ m



$\Delta g = 0.3$

$t \sim 1 - 40$ days

$\bar{t} \sim 5$ days

Work is going on both UA9 and LHCb